

## FFPF06U40DP

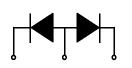
### **Features**

- Ultrafast with soft recovery
- · Low forward voltage

## **Applications**

- Power switching circuits
- Output rectifiers
- Freewheeling diodes
- Switching mode power supply





1. Cathode 2. Anode 3. Cathode

### **ULTRA FAST RECOVERY POWER RECTIFIER**

## Absolute Maximum Ratings (per diode) T<sub>C</sub>=25°C unless otherwise noted

| Symbol                           | Parameter   | Value        | Units |
|----------------------------------|---|--------------|-------|
| V <sub>RRM</sub>                 | Peak Repetitive Reverse Voltage                                 | 400          | V     |
| I <sub>F(AV)</sub>               | Average Rectified Forward Current @ T <sub>C</sub> = 100°C      | 6            | А     |
| I <sub>FSM</sub>                 | Non-repetitive Peak Surge Current<br>60Hz Single Half-Sine Wave | 60           | А     |
| T <sub>J,</sub> T <sub>STG</sub> | Operating Junction and StorageTemperature                       | - 65 to +150 | °C    |

### **Thermal Characteristics**

| Symbol |                   | Parameter                                    | Value | Units |  |
|--------|-------------------|--|-------|-------|--|
|        | R <sub>e.IC</sub> | Maximum Thermal Resistance, Junction to Case | 7.0   | °C/W  |  |

# Electrical Characteristics (per diode) T<sub>C</sub>=25 °C unless otherwise noted

| Symbol            | Parameter                             |   | Min. | Тур. | Max. | Units |
|-------------------|---------------------------------------|---|------|------|------|-------|
| V <sub>FM</sub> * | Maximum Instantaneous Forward Voltage |   |      |      |      | V     |
|                   | I <sub>F</sub> = 6A                   | T <sub>C</sub> = 25 °C                          | -    | -    | 1.4  |       |
|                   | I <sub>F</sub> = 6A                   | $T_C = 25 ^{\circ}C$<br>$T_C = 100 ^{\circ}C$   | -    | -    | 1.3  |       |
| I <sub>RM</sub> * | Maximum Instantaneous Reverse Current |   |      |      |      | μΑ    |
|                   | @ rated V <sub>R</sub>                | $T_C = 25  ^{\circ}C$                           | -    | -    | 20   |       |
|                   |                                       | $T_C = 25  ^{\circ}C$<br>$T_C = 100  ^{\circ}C$ | -    | -    | 200  |       |
| t <sub>rr</sub>   | Maximum Reverse Recovery Time         |   | -    | -    | 50   | ns    |
| I <sub>rr</sub>   | Maximum Reverse Recovery Current      |   | -    | -    | 4.0  | Α     |
| $\dot{Q}_{rr}$    | Maximum Reverse Recovery Charge       |   | -    | -    | 100  | nC    |
| ••                | (I <sub>F</sub> =6A, di/dt = 200A/μs) |   |      |      |      |       |
| W <sub>AVL</sub>  | Avalanche Energy                      |   | 1.0  | -    | -    | mJ    |

<sup>\*</sup> Pulse Test: Pulse Width=300µs, Duty Cycle=2%

# **Typical Characteristics**

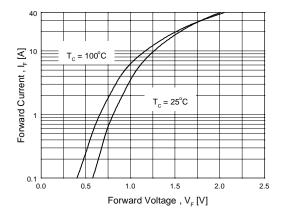


Figure 1. Typical Forward Voltage Drop vs. Forward Current

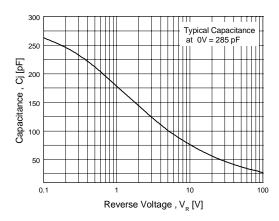


Figure 3. Typical Junction Capacitance

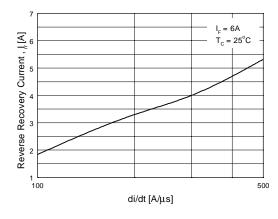


Figure 5. Typical Reverse Recovery Current vs. di/dt

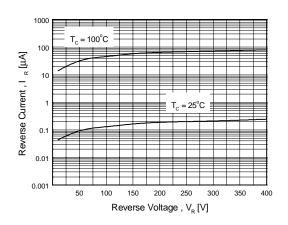


Figure 2. Typical Reverse Current vs. Reverse Voltage

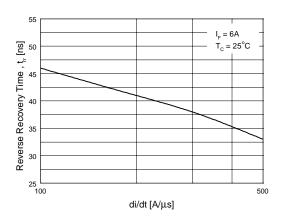


Figure 4. Typical Reverse Recovery Time vs. di/dt

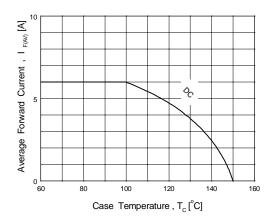
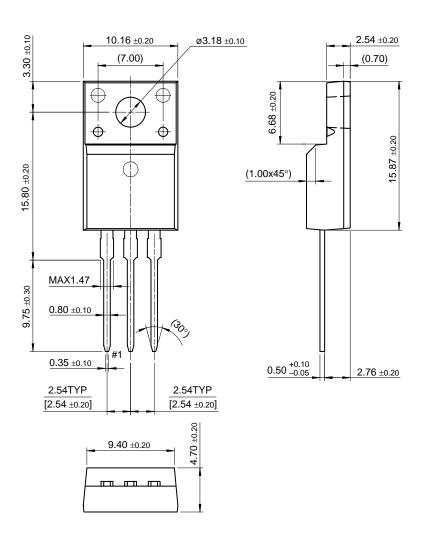


Figure 6. Forward Current Derating Curve

# **Package Dimensions**

# TO-220F



Dimensions in Millimeters

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